TAIWAN SEMICONDUCTOR

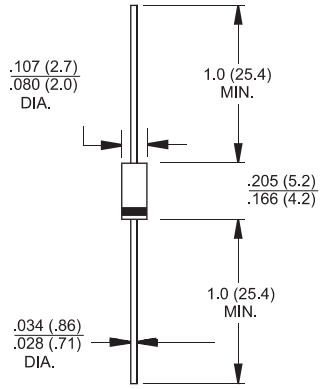
RoHS COMPLIANCE

1N5391S - 1N5399S

1.5 AMPS. Silicon Rectifiers

DO-41





Dimensions in inches and (millimeters)

Features

- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375",(9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Weight: 0.40 gram

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	1N 5391S	1N 5392S	1N 5393S	1N 5395S	1N 5397S	1N 5398S	1N 5399S	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T_A = 75 °C	$I_{(AV)}$	1.5							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage @ 1.5A	V_F	1.1	1.0						V
Maximum DC Reverse Current @ T_A=25 °C at Rated DC Blocking Voltage @ T_A=125 °C	I_R	5.0 50							uA uA
Maximum Full Load Reverse Current, Full Cycle Average .375"(9.5mm) Lead Length @T_A=75 °C	HT_{IR}	30							uA
Typical Junction Capacitance (Note 1)	Cj	30							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	50							°C/W
Operating Temperature Range	T_J	-65 to +125							°C
Storage Temperature Range	T_{STG}	-65 to +150							°C

Notes: 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
2. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

RATINGS AND CHARACTERISTIC CURVES (1N5391S THRU 1N5399S)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

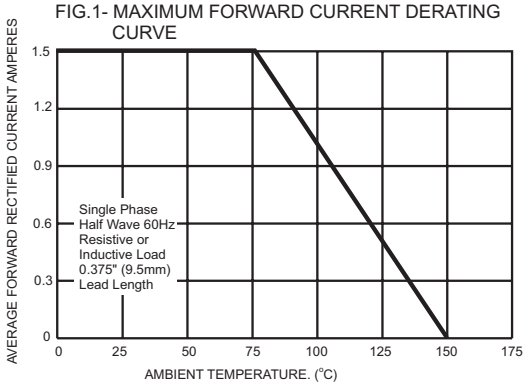


FIG.2- TYPICAL REVERSE CHARACTERISTICS

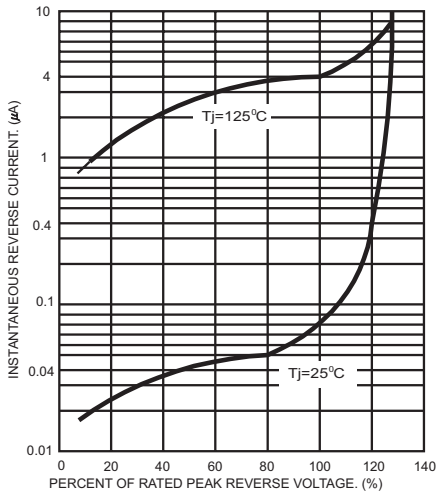


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

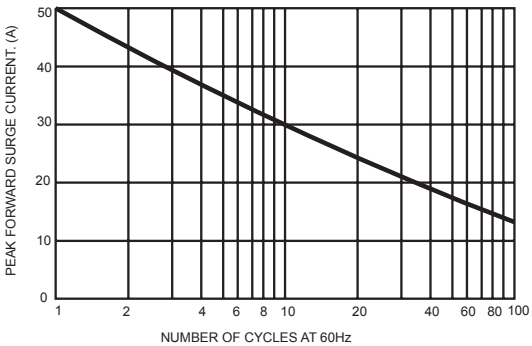


FIG.4- TYPICAL JUNCTION CAPACITANCE

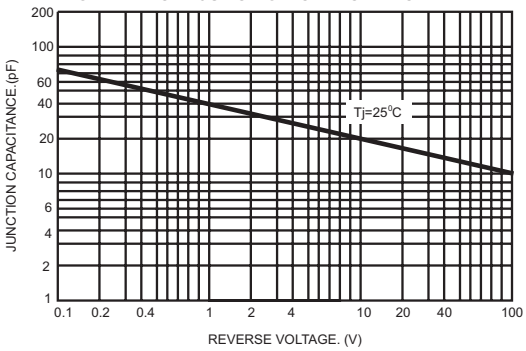


FIG.5- TYPICAL FORWARD CHARACTERISTICS

